



# ST303S SERIES

## INVERTER GRADE THYRISTORS

Stud Version

### Features

- All diffused design
- Center amplifying gate
- Guaranteed high dv/dt
- Guaranteed high di/dt
- High surge current capability
- Low thermal impedance
- High speed performance

300A

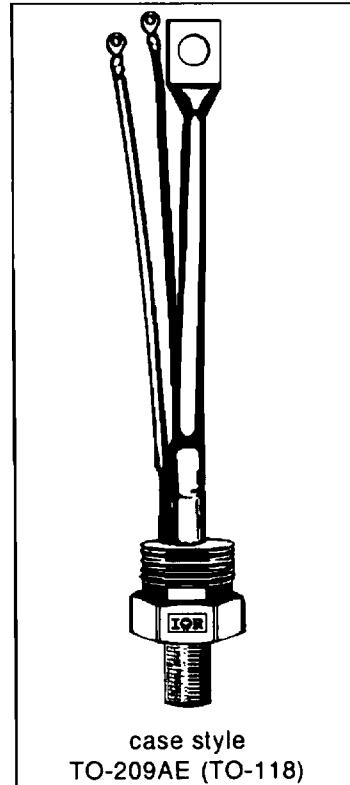
### Typical Applications

- Inverters
- Choppers
- Induction heating
- All types of force-commutated converters

### Major Ratings and Characteristics

Parameters	ST303S	Units
$I_{T(AV)}$	300	A
@ $T_c$	65	°C
$I_{T(RMS)}$	471	A
$I_{TSM}$	7950	A
@ 60Hz	8320	A
$I^2t$	316	KA <sup>2</sup> s
@ 60Hz	288	KA <sup>2</sup> s
$V_{DRM}/V_{RRM}$	400 to 1200	V
$t_q$ range (*)	10 to 30	μs
$T_J$	- 40 to 125	°C

(\*)  $t_q = 10$  to  $20\mu s$  for 400 to 800V devices  
 $t_q = 15$  to  $30\mu s$  for 1000 to 1200V devices



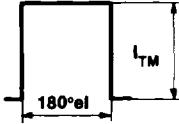
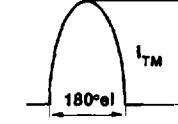
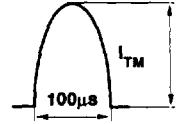
## ST303S Series

### ELECTRICAL SPECIFICATIONS

#### Voltage Ratings

Type number	Voltage Code	$V_{DRM}/V_{RRM}$ , maximum repetitive peak voltage V	$V_{RSM}$ , maximum non-repetitive peak voltage V	$I_{DRM}/I_{RRM}$ max. @ $T_j = T_{j\max}$ mA
ST303S	04	400	500	50
	08	800	900	
	10	1000	1100	
	12	1200	1300	

#### Current Carrying Capability

Frequency					Units		
50Hz	670	470	1050	940	5240	4300	A
400Hz	480	330	1021	710	1800	1270	
1000Hz	230	140	760	470	730	430	
2500Hz	35	-	150	-	90	-	
Recovery voltage $V_r$	50	50	50	50	50	50	V
Voltage before turn-on $V_d$	$V_{DRM}$	$V_{DRM}$	$V_{DRM}$				
Rise of on-state current $dI/dt$	50	50	-	-	-	-	A/ $\mu$ s
Case temperature	40	65	40	65	40	65	°C
Equivalent values for RC circuit	10Ω / 0.47μF		10Ω / 0.47μF		10Ω / 0.47μF		

#### On-state Conduction

Parameter	ST303S	Units	Conditions		
$I_{T(AV)}$ Max. average on-state current @ Case temperature	300	A	180° conduction, half sine wave		
	65	°C			
$I_{T(RMS)}$ Max. RMS on-state current	471	A	DC @ 45°C case temperature		
$I_{TSM}$ Max. peak, one half cycle, non-repetitive surge current	7950		$t = 10ms$	No voltage reapplied	Sinusoidal half wave, Initial $T_j = T_{j\max}$
	8320				
	6690		$t = 10ms$	100% $V_{RRM}$ reapplied	
	7000		$t = 8.3ms$	reapplied	
$I^2t$ Maximum $I^2t$ for fusing	316	KA <sup>2</sup> s	$t = 10ms$	No voltage reapplied	
	288		$t = 8.3ms$	reapplied	
	224		$t = 10ms$	100% $V_{RRM}$ reapplied	
	204		$t = 8.3ms$	reapplied	
$I^2/t$ Maximum $I^2/t$ for fusing	3160	KA <sup>2</sup> /s	$t = 0.1$ to 10ms, no voltage reapplied		

## On-state Conduction

Parameter	ST303S	Units	Conditions
$V_{TM}$	Max. peak on-state voltage	2.16	$I_{TM} = 1255A, T_J = T_J \text{ max}, t_p = 10\text{ms sine wave pulse}$ $(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}, T_J = T_J \text{ max.})$
$V_{T(TO)1}$	Low level value of threshold voltage	1.44	
$V_{T(TO)2}$	High level value of threshold voltage	1.46	
$r_{f1}$	Low level value of forward slope resistance	0.57	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}, T_J = T_J \text{ max.})$ $(I > \pi \times I_{T(AV)}, T_J = T_J \text{ max.})$
$r_{f2}$	High level value of forward slope resistance	0.56	
$I_H$	Maximum holding current	600	$T_J = 25^\circ\text{C}, I_T > 30\text{A}$ $T_J = 25^\circ\text{C}, V_A = 12\text{V}, R_a = 6\Omega, I_G = 1\text{A}$
$I_L$	Typical latching current	1000	

## Switching

Parameter	ST303S	Units	Conditions
$di/dt$	Max. non-repetitive rate of rise of turned-on current	1000	$T_J = T_J \text{ max}, V_{DRM} = \text{rated } V_{DRM}$ $I_{TM} = 2 \times di/dt$
$t_d$	Typical delay time	0.80	$T_J = 25^\circ\text{C}, V_{DM} = \text{rated } V_{DRM}, I_{TM} = 50\text{A DC}, t_p = 1\mu\text{s}$ Resistive load, Gate pulse: 10V, 5Ω source
$t_q$	Max. turn-off time (*)	Min 10 Max 30	
			$T_J = T_J \text{ max}, I_{TM} = 550\text{A, commutating } di/dt = 40\text{A}/\mu\text{s}$ $V_R = 50\text{V}, t_p = 500\mu\text{s}, dv/dt: \text{see table in device code}$

(\*)  $t_q = 10$  to  $20\mu\text{s}$  for 400 to 800V devices;  $t_q = 15$  to  $30\mu\text{s}$  for 1000 to 1200V devices.

## Blocking

Parameter	ST303S	Units	Conditions
$dv/dt$	Maximum critical rate of rise of off-state voltage	500	$T_J = T_J \text{ max, linear to 80\% } V_{DRM}$ , higher value available on request
$I_{RRM}$ $I_{DRM}$	Max. peak reverse and off-state leakage current	50	$T_J = T_J \text{ max, rated } V_{DRM}/V_{RRM} \text{ applied}$

## Triggering

Parameter	ST303S	Units	Conditions
$P_{GM}$	Maximum peak gate power	60	
$P_{G(AV)}$	Maximum average gate power	10	$T_J = T_J \text{ max, f} = 50\text{Hz, d\%} = 50$
$I_{GM}$	Max. peak positive gate current	10	$T_J = T_J \text{ max, } t_p \leq 5\text{ms}$
$+V_{GM}$	Maximum peak positive gate voltage	20	
$-V_{GM}$	Maximum peak negative gate voltage	5	$T_J = T_J \text{ max, } t_p \leq 5\text{ms}$
$I_{GT}$	Max. DC gate current required to trigger	200	$T_J = 25^\circ\text{C}, V_A = 12\text{V, R}_a = 6\Omega$
$V_{GT}$	Max. DC gate voltage required to trigger	3	
$I_{GD}$	Max. DC gate current not to trigger	20	$T_J = T_J \text{ max, rated } V_{DRM} \text{ applied}$
$V_{GD}$	Max. DC gate voltage not to trigger	0.25	

# ST303S Series

## Thermal and Mechanical Specifications

Parameter	ST303S	Units	Conditions
T <sub>J</sub> Max. junction operating temperature range	-40 to 125	°C	
T <sub>stg</sub> Max. storage temperature range	-40 to 150		
R <sub>thJC</sub> Max. thermal resistance, junction to case	0.10	K/W	DC operation
R <sub>thCS</sub> Max. thermal resistance, case to heatsink	0.03		Mounting surface, smooth, flat and greased
T Mounting torque, ± 10%	48.5 (425)	Nm (lbf-in)	Non lubricated threads
wt Approximate weight	535	g	
Case style	TO-209AE (TO-118)		See Outline Table

### ΔR<sub>thJC</sub> Conduction

(The following table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.011	0.008	K/W	T <sub>J</sub> = T <sub>J</sub> max.
120°	0.013	0.014		
90°	0.017	0.018		
60°	0.025	0.026		
30°	0.041	0.042		

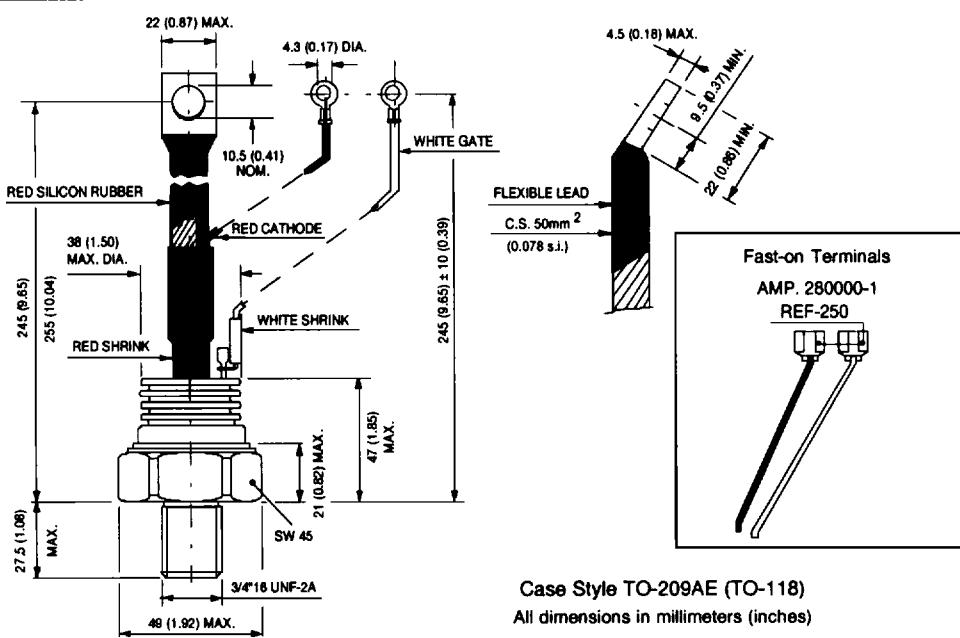
## Ordering Information Table

Device Code	ST	30	3	S	12	P	F	N	0																																											
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)	(10)																																										
<b>1 - Thyristor</b>																																																				
<b>2 - Essential part number</b>																																																				
<b>3 - 3 = Fast turn off</b>																																																				
<b>4 - S = Compression bonding Stud</b>																																																				
<b>5 - Voltage code: Code x 100 = V<sub>RRM</sub> (See Voltage Ratings table)</b>																																																				
<b>6 - P = Stud base 3/4" 16UNF-2A</b>																																																				
<b>M = Stud base metric threads M24 x 1.5</b>																																																				
<b>7 - Reapplied dv/dt code (for t<sub>q</sub> test condition)</b>																																																				
<b>8 - t<sub>q</sub> code</b>																																																				
<b>9 - 0 = Eyelet terminals (Gate and Aux. Cathode Leads)</b>																																																				
1 = Fast-on terminals (Gate and Aux. Cathode Leads)																																																				
3 = Threaded top terminal 3/8" 24UNF-2A																																																				
<b>10 - Critical dv/dt:</b>																																																				
None = 500V/μsec (Standard value)																																																				
L = 1000V/μsec (Special selection)																																																				
<b>dv/dt - t<sub>q</sub> combinations available</b>																																																				
<table border="1"> <thead> <tr> <th>t<sub>q</sub>(μs)</th> <th>dv/dt (V/μs)</th> <th>20</th> <th>50</th> <th>100</th> <th>200</th> <th>400</th> </tr> </thead> <tbody> <tr> <td>10</td> <td>CN</td> <td>DN</td> <td>EN</td> <td>FN *</td> <td>HN</td> <td></td> </tr> <tr> <td>12</td> <td>CM</td> <td>DM</td> <td>EM</td> <td>FM</td> <td>HM</td> <td></td> </tr> <tr> <td>up to 800V</td> <td>CL</td> <td>DL</td> <td>EL</td> <td>FL *</td> <td>HL</td> <td></td> </tr> <tr> <td>15</td> <td>CK</td> <td>EK</td> <td></td> <td>FK *</td> <td>HK</td> <td></td> </tr> <tr> <td>20</td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> </tr> </tbody> </table>											t <sub>q</sub> (μs)	dv/dt (V/μs)	20	50	100	200	400	10	CN	DN	EN	FN *	HN		12	CM	DM	EM	FM	HM		up to 800V	CL	DL	EL	FL *	HL		15	CK	EK		FK *	HK		20						
t <sub>q</sub> (μs)	dv/dt (V/μs)	20	50	100	200	400																																														
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30	—	DH	EH																																																	

\*Standard part number.  
All other types available only on request.

## Outline Table

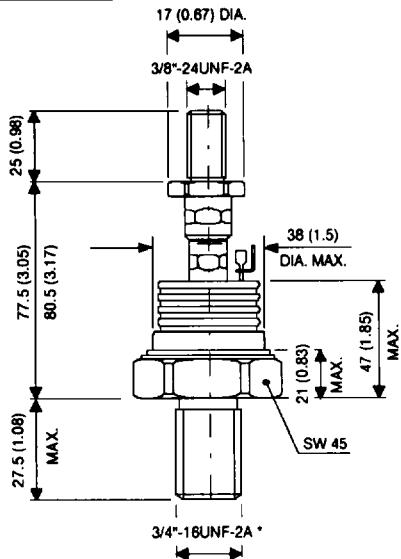
## CERAMIC HOUSING



\* FOR METRIC DEVICE: M24 X 1.5 - LENGTH SCREW 21 (0.83) MAX.

INV SCR  
STUD

## CERAMIC HOUSING



\* FOR METRIC DEVICE: M24 x 1.5 - LENGTH SCREW 21 (0.83) MAX.

## ST303S Series

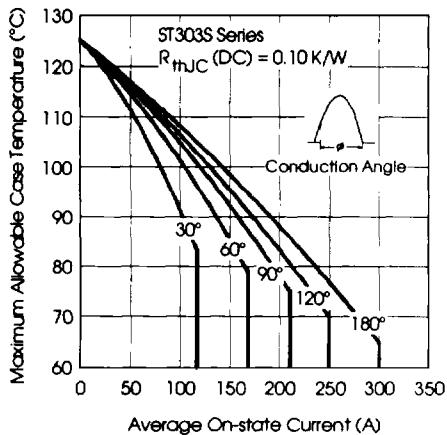


Fig. 1 - Current Ratings Characteristics

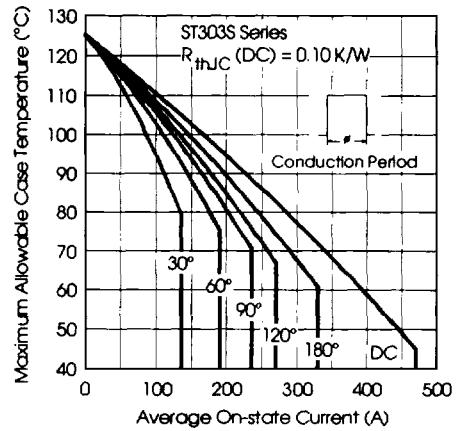


Fig. 2 - Current Ratings Characteristics

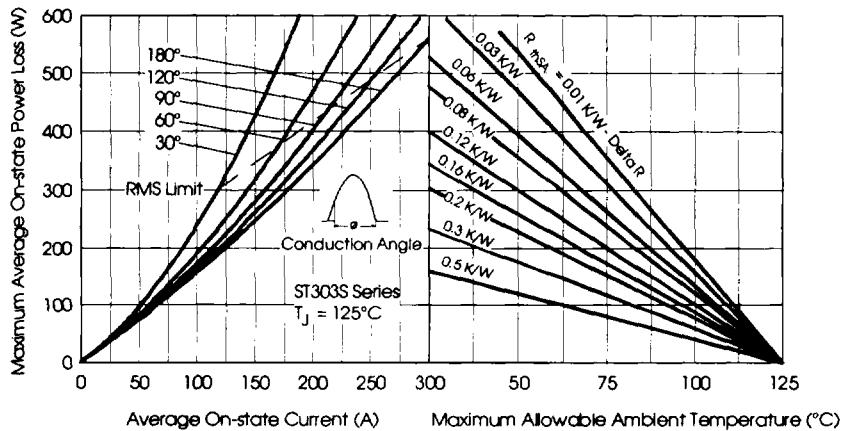


Fig. 3 - On-state Power Loss Characteristics

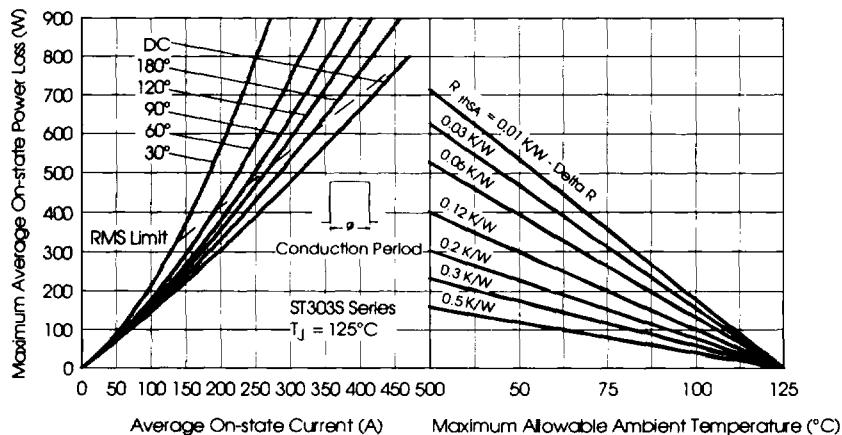


Fig. 4 - On-state Power Loss Characteristics

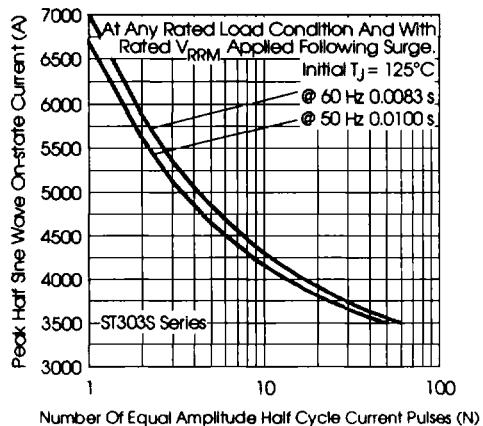


Fig. 5 - Maximum Non-repetitive Surge Current

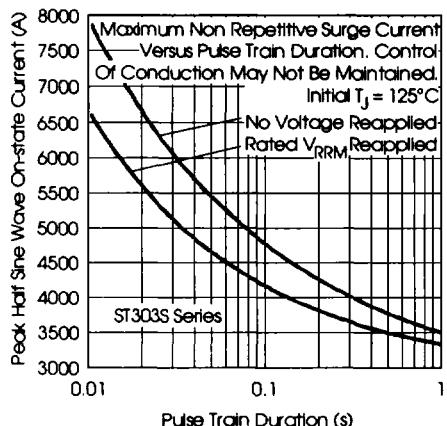


Fig. 6 - Maximum Non-repetitive Surge Current

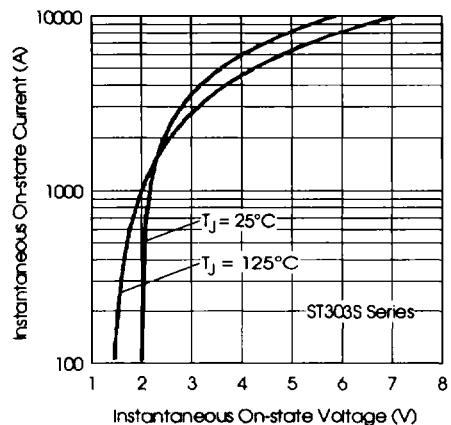


Fig. 7 - On-state Voltage Drop Characteristics

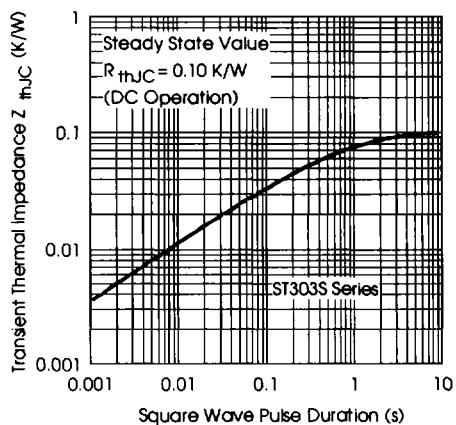


Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristic

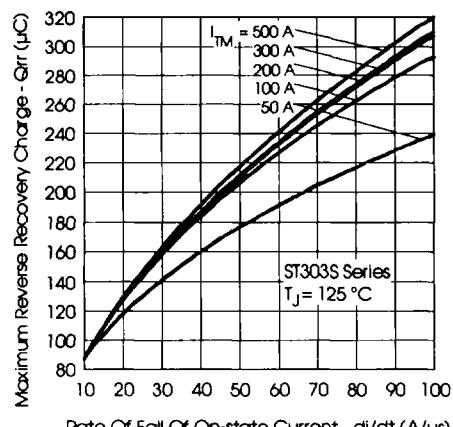


Fig. 9 - Reverse Recovered Charge Characteristics

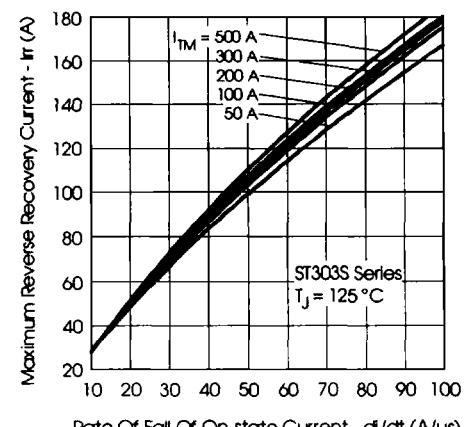


Fig. 10 - Reverse Recovery Current Characteristics

INV SCR  
STUD  
MTD

## ST303S Series

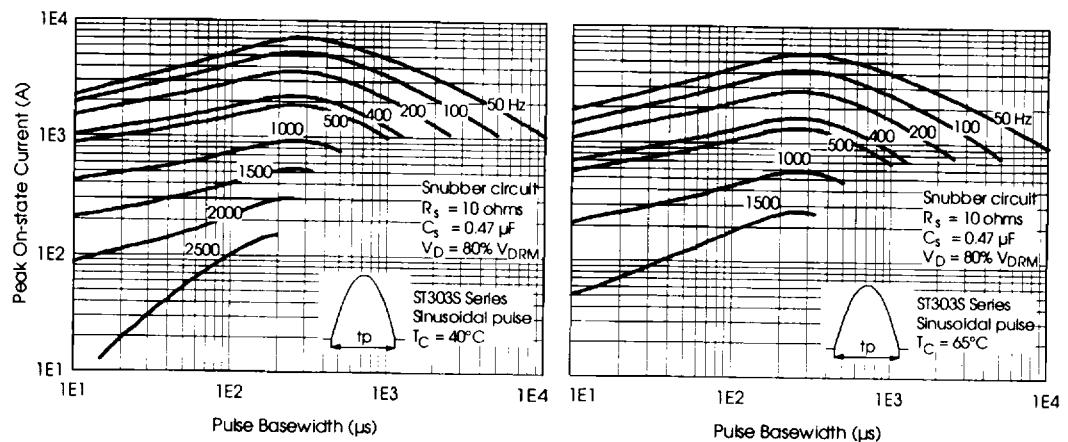


Fig. 11 - Frequency Characteristics

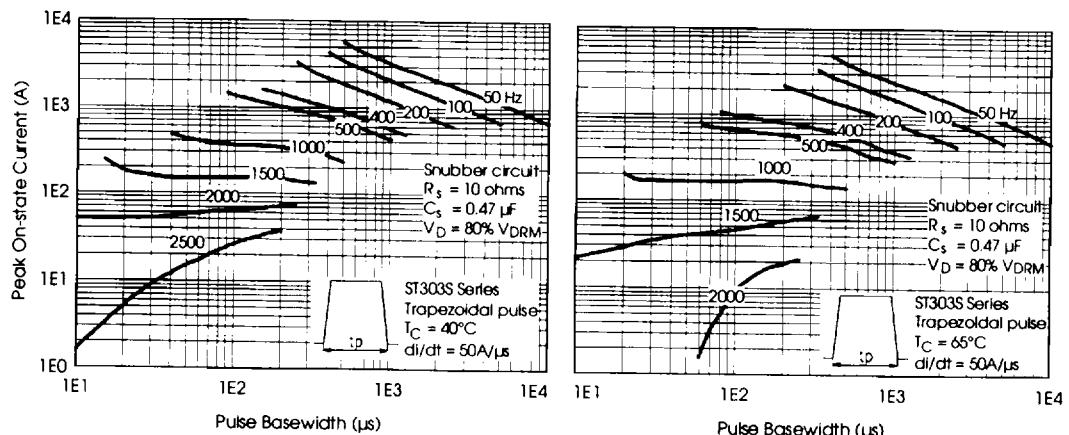


Fig. 12 - Frequency Characteristics

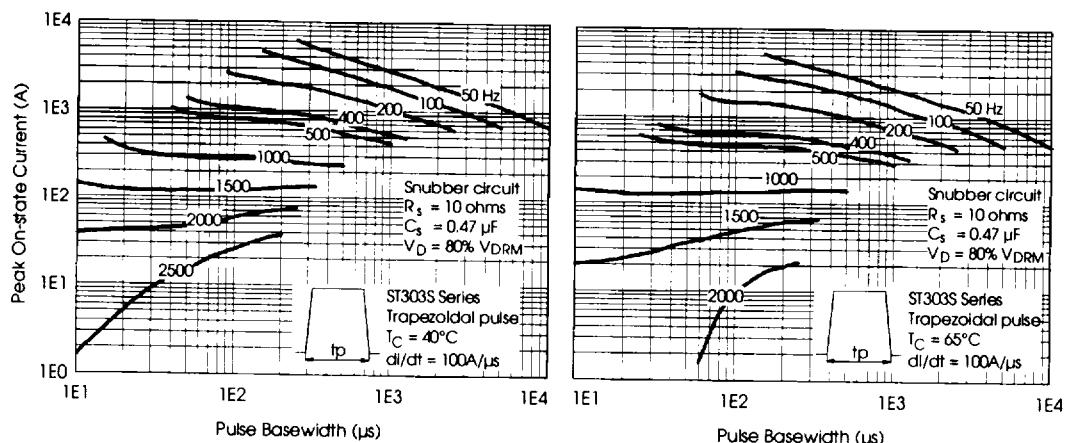


Fig. 13 - Frequency Characteristics

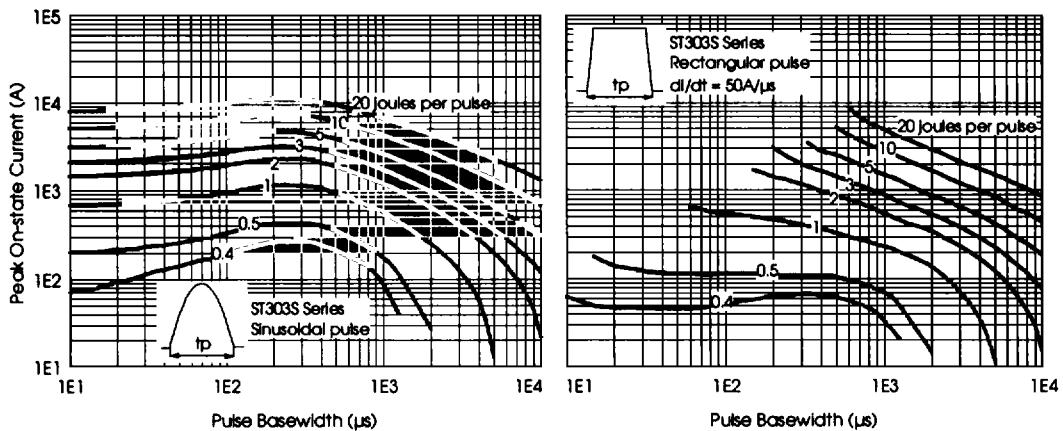


Fig. 14 - Maximum On-state Energy Power Loss Characteristics

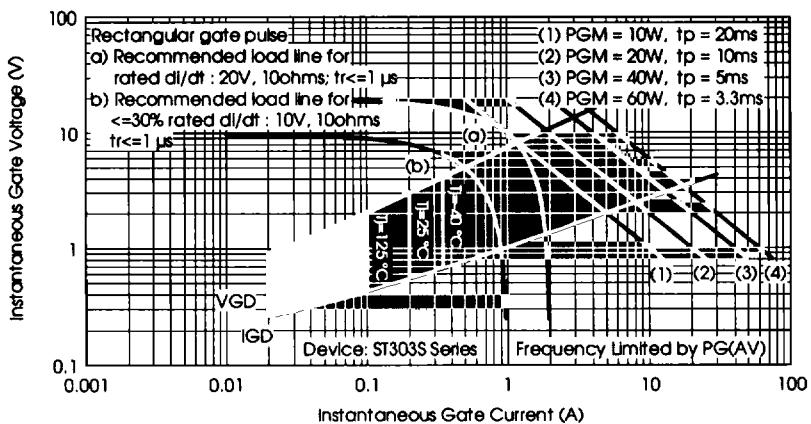


Fig. 15 - Gate Characteristics

IHW SCR  
SIUD  
MTD